

STTH1R06

Turbo 2 ultrafast high voltage rectifier

Features

- Ultrafast switching
- Low reverse recovery current
- Low thermal resistance
- Reduces switching and conduction losses

Description

The STTH1R06, which is using ST Turbo 2 600 V technology, is specially suited as boost diode in power factor correction circuitry.

The device is also intended for use as a free wheeling diode in power supplies and other power switching applications.

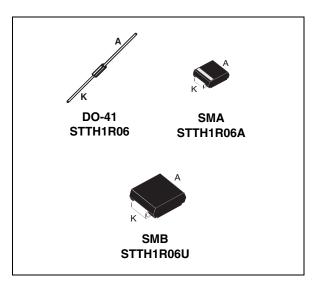


Table 1. Device summary

Symbol	Value
I _{F(AV)}	1 A
V_{RRM}	600 V
I _R (max)	75 µA
T _j	175 °C
V _F (typ)	1.0 V
t _{rr} (max)	25 ns

October 2009 Doc ID 10203 Rev 5 1/9

Characteristics STTH1R06

1 Characteristics

Table 2. Absolute ratings (limiting values)

Symbol	Param	Value	Unit		
V _{RRM}	Repetitive peak reverse voltage			600	V
	Forward rms current	DO-41		10	Α
I _{F(RMS)}	Forward mis current	SMA / SMB		7	A
		DO-41	$T_c = 100 ^{\circ}\text{C} \delta = 0.5$		
I _{F(AV)}	(AV) Average forward current	SMA	$T_{c} = 125 ^{\circ}\text{C} \delta = 0.5$	1	Α
			$T_c = 135 ^{\circ}C \delta = 0.5$		
	Curae non repetitive femuera current	DO-41	t - 10ma ainuaaidal	25	Α
IFSM	Surge non repetitive forward current	SMA / SMB	$t_p = 10$ ms sinusoidal	20	^
T _{stg}	Storage temperature range	-65 to + 175	°C		
T _j	Maximum operating junction temperature			175	°C

Table 3. Thermal resistance

Symbol	Parameter			Value (max)	Unit
		L = 10 mm	DO-41	45	
R _{th(j-l)}	Junction to lead		SMA	30	°C/W
			SMB	25	
R _{th(j-a)}	Junction to ambient ⁽¹⁾	L = 10 mm	DO-41	70	°C/W

^{1.} $R_{th(j-a)}$ is measured with a copper area S = Scm2 (see *Figure 14*).

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
	$T_j = 25^{\circ}$		V - V			1	μA
I'R	Reverse leakage current	Perse leakage current $T_j = 150 ^{\circ}\text{C}$ $V_R = V_{RRM}$			10	75	μΑ
V	Forward voltage drop	T _j = 25 °C				1.7	V
V _F	V _F Forward voltage drop		I _F = 1A		1.0	1.25	V

To evaluate the conduction losses use the following equation: $P = 1.03 \text{ x I}_{F(AV)} + 0.27 \text{ I}_{F}^2(RMS)$

STTH1R06 **Characteristics**

Table 5. **Dynamic characteristics**

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
+	Reverse recovery	T = 25 °C	$I_F = 0.5A$ $I_{rr} = 0.25A$ $I_R = 1A$ $I_F = 1A$ $dI_F/dt = -50$ A/ μ s $V_B = 30$ V			25	ns
t _{rr}	time	1 _j = 23 0	$I_F = 1A dI_F/dt = -50 A/\mu s V_R = 30V$		30	45	115
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 1A$ $dI_F/dt = 100 A/\mu s$ $V_{FR} = 1.1 x V_{Fmax}$			100	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 1A$ $dI_F/dt = 100 A/\mu s$ $V_{FR} = 1.1 x V_{Fmax}$			10	V

Figure 1. Conduction losses versus average Figure 2. Forward voltage drop vs forward forward current current

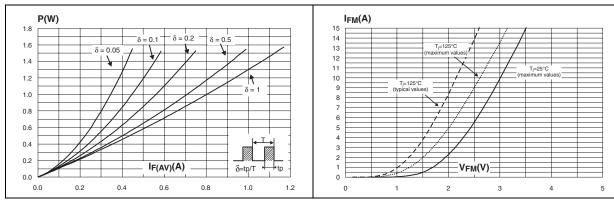


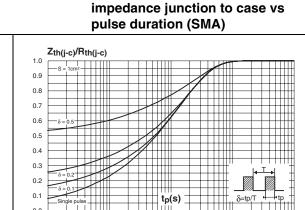
Figure 4.

0.0

1.E-01

1.E+00

Figure 3. **Relative variation of thermal** impedance junction to case vs pulse duration (DO-41)



1.E+01

1.E+02

1.E+03

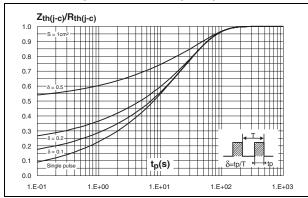
Relative variation of thermal

 $Z_{th(j-c)}/R_{th(j-c)}$ 1.0 0.9 0.8 0.7 0.6 0.5 0.4 0.3 0.2 0.1 δ=tp/T 0.0 1.E-01 1.E+00 1.E+01 1.E+02 1.E+03

Characteristics STTH1R06

Figure 5. Relative variation of thermal impedance junction to case vs pulse duration (SMB)

Figure 6. Peak reverse recovery current vs dl_F/dt (typical values)



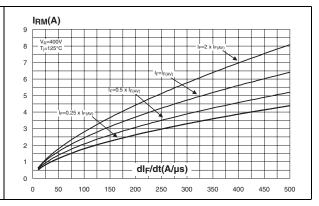
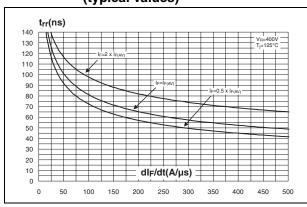


Figure 7. Reverse recovery time versus dl_F/dt Figure 8. Reverse recovery charges versus (typical values)



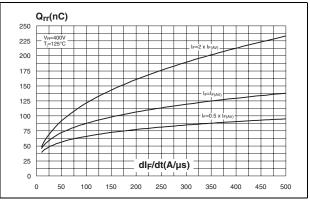
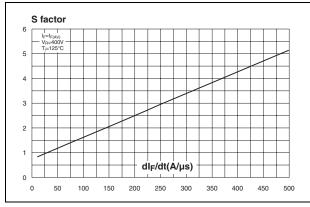
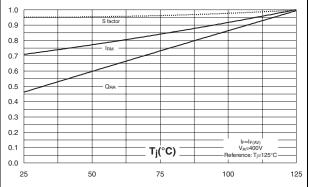


Figure 9. Reverse recovery softness factor vs dl_F/dt (typical values)

Figure 10. Relative variations of dynamic parameters vs junction temperature

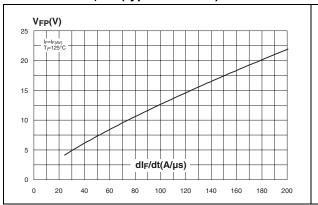




4/9 Doc ID 10203 Rev 5

STTH1R06 Characteristics

Figure 11. Transient peak forward voltage vs Figure 12. Forward recovery time vs dl_F/dt dl_F/dt (typical values) (typical values)



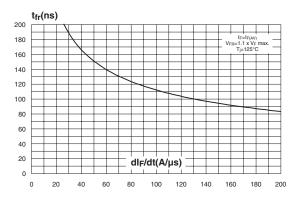
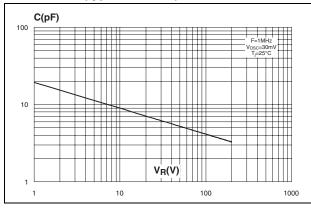


Figure 13. Junction capacitance versus reverse voltage applied (typical values)

Figure 14. Thermal resistance junction to ambient versus copper surface under each lead



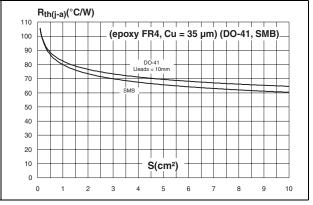
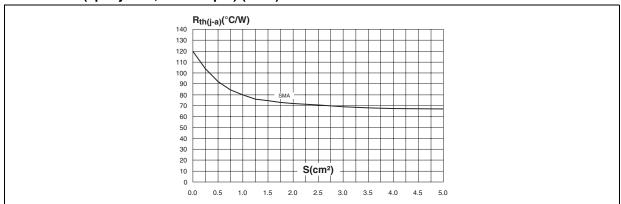


Figure 15. Thermal resistance junction to ambient versus copper surface under each lead (epoxy FR4, $Cu = 35 \mu m$) (SMA)



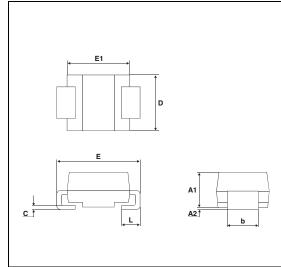
Package information STTH1R06

2 Package information

- Epoxy meets UL94, V0
- Lead-free packages

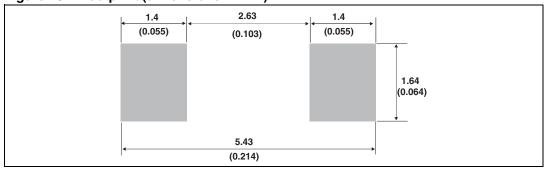
In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

Table 6. SMA dimensions



	Dimensions				
Ref.	Millim	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.094	
A2	0.05	0.20	0.002	0.008	
b	1.25	1.65	0.049	0.065	
С	0.15	0.40	0.006	0.016	
D	2.25	2.90	0.089	0.114	
Е	4.80	5.35	0.189	0.211	
E1	3.95	4.60	0.156	0.181	
L	0.75	1.50	0.030	0.059	

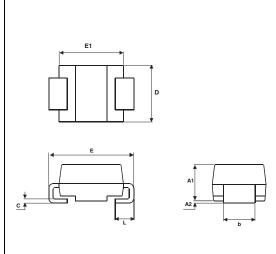
Figure 16. Footprint (dimensions in mm)



6/9 Doc ID 10203 Rev 5

STTH1R06 Package information

Table 7. SMB dimensions



	Dimensions				
Ref.	Millim	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
A1	1.90	2.45	0.075	0.096	
A2	0.05	0.20	0.002	0.008	
b	1.95	2.20	0.077	0.087	
С	0.15	0.40	0.006	0.016	
Е	5.10	5.60	0.201	0.220	
E1	4.05	4.60	0.159	0.181	
D	3.30	3.95	0.130	0.156	
L	0.75	1.50	0.030	0.059	

Figure 17. Footprint (dimensions in mm)

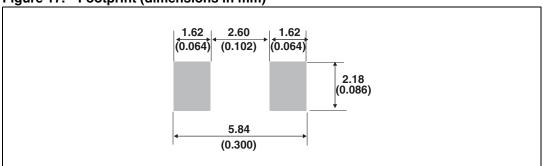
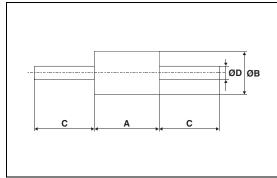


Table 8. DO-41 (plastic) dimensions



	Dimensions				
Ref.	Millin	neters	Inc	hes	
	Min.	Max.	Min.	Max.	
Α	4.07	5.20	0.160	0.205	
В	2.04	2.71	0.080	0.107	
С	25.4		1		
D	0.71	0.86	0.028	0.034	

Ordering information STTH1R06

3 Ordering information

Table 9. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH1R06	STTH1R06	DO-41	0.34 g	2000	Ammopack
STTH1R06RL	STTH1R06	DO-41	0.34 g	5000	Tape and reel
STTH1R06A	HR6	SMA	0.068 g	5000	Tape and reel
STTH1R06U	BR6	SMB	0.11 g	2500	Tape and reel

4 Revision history

Table 10. Document revision history

Date	Revision	Changes
Apr-2003	1	First issue.
07-Sep-2004	2	DO-41 and SMA packages added.
24-Feb-2005	3	SMA package dimensions update. Reference A1 max. changed from 2.70 mm (0.106 inc.) to 2.03 mm (0.080).
02-Jul-2007	4	Reformatted to current standards. Added cathode bars to cover illustrations. Updated dimensions and footprint illustrations for SMA and SMB packages. Corrected part number in Table 9.
30-Sep-2009	5	Updated table 8 package dimensions.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com



Doc ID 10203 Rev 5

9/9